

Features

- Split Gate Trench MOSFET Technology
- Low R_{DS(on)} & FOM
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free. "Green" Device(Note1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

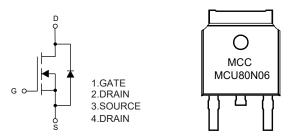
- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range : -55°C to +175°C
- Thermal Resistance:50°C/W Junction to Ambient^(Note2)
- Thermal Resistance : 1.6°C/W Junction to Case

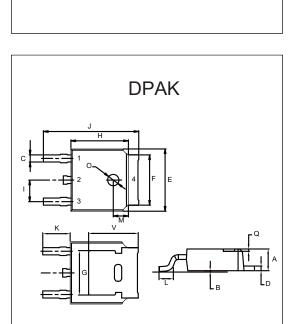
Parameter		Symbol	Rating	Unit	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Volltage		V _{GS}	±20	V	
Continuous Drain Current	T _C =25°C		80		
	T _C =100°C	I _D	56	A	
Pulsed Drain Current ^(Note2)		I _{DM}	320	Α	
Total Power Dissipation ^(Note3)		P _D	94	W	
Single Pulsed Avalanche Energy ^(Note4)		E _{AS}	150	mJ	

Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\rm 0JA}$ is measured with the device mounted on $1 in^2$ FR-4 board with 2oz.
- Copper, in a still air environment with $T_A = 25^{\circ}C$.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-case thermal resistance.
- 5. T_J =25°C, V_{DD} =40V, V_{GS} =10V, L=0.5mH.

Internal Structure and Marking Code





N-CHANNEL

MOSFET

DIM	INCHES		MM		NOTE
DIN	MIN	MAX	MIN	MAX	NOTE
А	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
Н	0.236	0.244	6.00	6.20	
Ι	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
Κ	0.114		2.	90	TYP.
L	0.055	0.067	1.40	1.70	
М	0.063		1.	60	TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.	35	TYP.

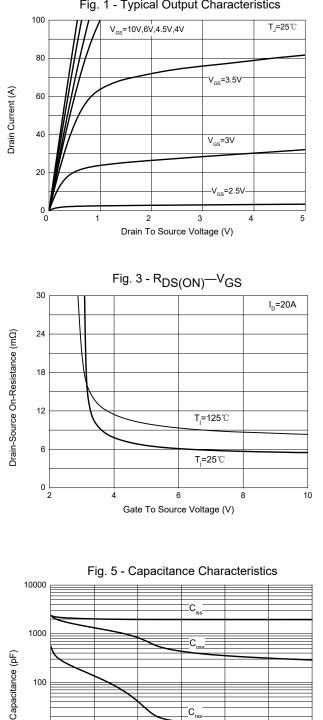


Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit	
Static Characteristics					1	I	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} =0V, I_{D} =250 μ A	60			V	
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μA	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.2	1.7	2	V	
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		5.5 7.5		mΩ	
		V _{GS} =4.5V, I _D =10A	7		9.5	11152	
Gate Resistance	R _g	f=1 MHz, Open drain		1.5		Ω	
Diode Characteristics							
Continuous Body Diode Current	I _S				80	А	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =30A			1.2	V	
Reverse Recovery Time	t _{rr}			37		ns	
Reverse Recovery Charge	Q _{rr}	I _F =30A, dI _F /dt=100A/μs		30		nC	
Dynamic Characteristics				1	+		
Input Capacitance	C _{iss}			1957			
Output Capacitance	C _{oss}	V _{DS} =30V,V _{GS} =0V,f=1MHz		436		pF	
Reverse Transfer Capacitance	C _{rss}			15			
Total Gate Charge	Qg			32.4			
Gate-Source Charge	Q _{gs}	V_{DS} =30V, V_{GS} =10V, I_{D} =20A		5.2		nC	
Gate-Drain Charge	Q _{gd}			5.6			
Turn-On Delay Time	t _{d(on)}			8.6			
Turn-On Rise Time	t _r	V _{DD} =30V, V _{GS} =10V,		4.8		- ns	
Turn-Off Delay Time	t _{d(off)}	R_{GEN} =3 Ω , I_{DS} =2A		30.4			
Turn-Off Fall Time	t _f			23.1			



Curve Characteristics



C_{rs}

30

Drain To Source Voltage (V)

40

50

60

Fig. 1 - Typical Output Characteristics

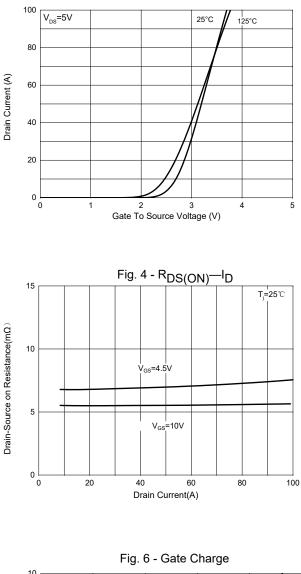
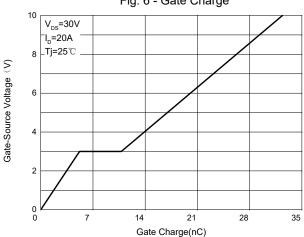


Fig. 2 - Transfer Characteristics



100

10

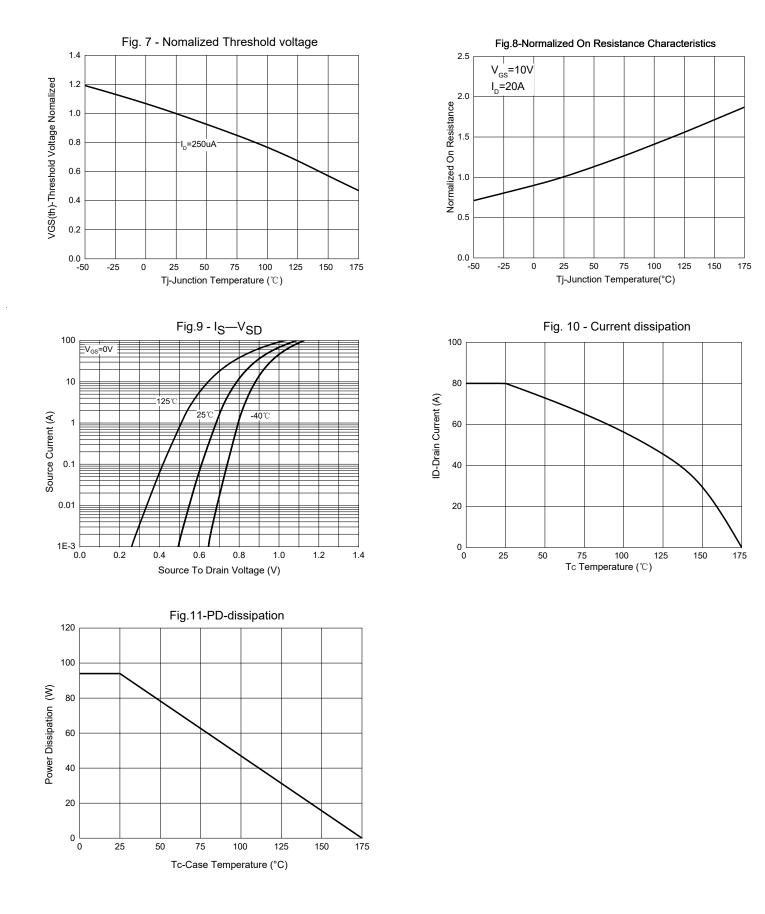
1 L 0

10

20

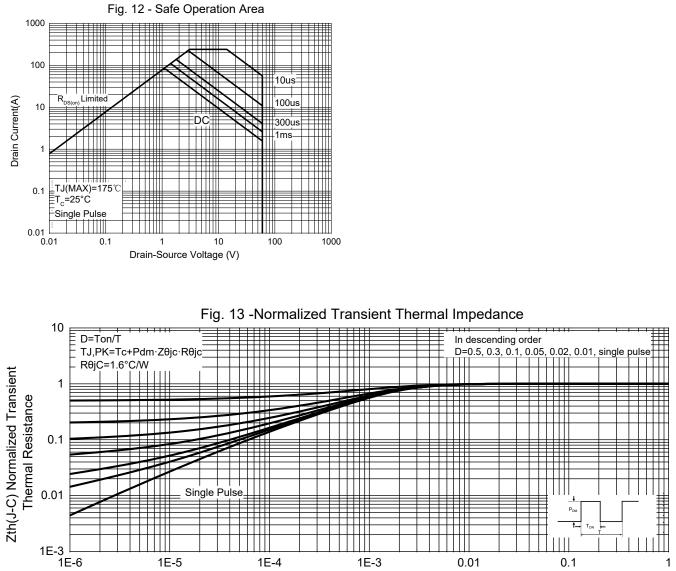


Curve Characteristics





Curve Characteristics



Pulse Width (s)



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:2.5Kpcs/Reel

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